

## Investigating Connection Repeatability of Waveguide Devices at Frequencies from 750 GHz to 1.1 THz

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### Overview

- Background
- Experimental Method
- Data Analysis
- Results
- Observations
- Uncertainty Considerations
- Summary

## Background

- In recent years, the upper frequency limit of VNAs has increased to 1.1 THz
- Most VNAs above 110 GHz use waveguide as the test ports
- The size of waveguide above 110 GHz is often very small (e.g. 250  $\mu\text{m}$  x 125  $\mu\text{m}$  at 1.1 THz)
- Connection alignment for these small waveguides can cause large measurement errors

## Background (contd)

- Connection repeatability of small waveguides introduces random errors into the VNA measurements
- This work investigates the likely size of these errors for measurements in WM-250 (WR-01) from 750 GHz to 1.1 THz
- A framework is also described for accommodating these errors into an overall uncertainty budget for VNAs operating from 750 GHz to 1.1 THz and other submillimeter-wave frequency bands

## Experimental Method

Agilent PNA-X VNA with VDI Extender Heads: 750 GHz to 1100 GHz

Situated at:  
*'The Roger Pollard  
High Frequency  
Measurements  
Laboratory'*

University of Leeds  
UK



## Experimental Method (contd)

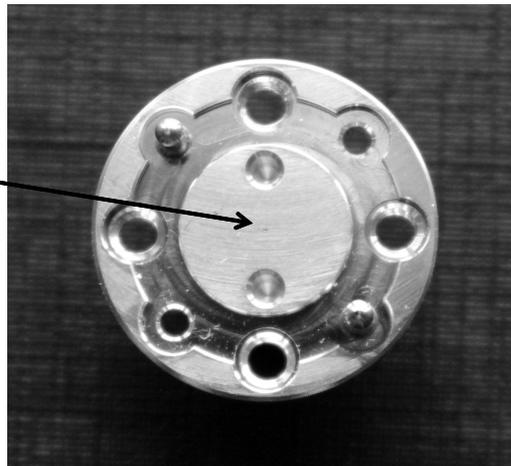
VNA Test Ports

Aperture:

- WM-250 (WR-01)  
250  $\mu\text{m}$   $\times$  125  $\mu\text{m}$

Flange/interface:

- $\frac{3}{4}$ " round (UG-387)
- 4 outer alignment pins  
used for flange alignment



## Experimental Method (contd)

Test conditions:

- Input power level  $\approx -35$  dBm ( $0.3 \mu\text{W}$ )
- IF bandwidth: 30 Hz
- Averaging factor = 1 (i.e. no numerical averaging)
- Frequency range: 750 GHz to 1100 GHz
- Frequency step size: 1.75 GHz (i.e. 201 points)

## Experimental Method (contd)

Calibration:

- One-port calibration, using three 'known' loads
- Flush Short / Offset Short / Near-matched load

Repeatability:

- Devices: the same three calibration standards
- 12 disconnect/reconnects for each device
- No flange inversion between disconnect/reconnects

Measurand:

- Complex-valued linear reflection coefficient

## Data analysis

We use the experimental standard deviation as the measure of variability in the observed repeatability values

Let  $\Gamma$  be the complex-valued linear reflection coefficient written in terms of its real,  $\Gamma_R$ , and imaginary,  $\Gamma_I$ , components:

$$\Gamma = \Gamma_R + j \Gamma_I$$

(with  $j^2 = -1$ )

We make  $n$  repeated determinations of  $\Gamma$  (in our case, we have chosen  $n = 12$ )

## Data analysis (contd)

### Real component, $\Gamma_R$

Experimental variance:

$$s^2(\Gamma_{R_i}) = \frac{1}{n-1} \sum_{k=1}^n (\Gamma_{R_k} - \bar{\Gamma}_R)^2$$

where

$$\bar{\Gamma}_R = \frac{1}{n} \sum_{i=1}^n \Gamma_{R_i}$$

Experimental standard deviation,  $s(\Gamma_{R_i})$ , is the positive square root of  $s^2(\Gamma_{R_i})$

### Imaginary component, $\Gamma_I$

Experimental variance:

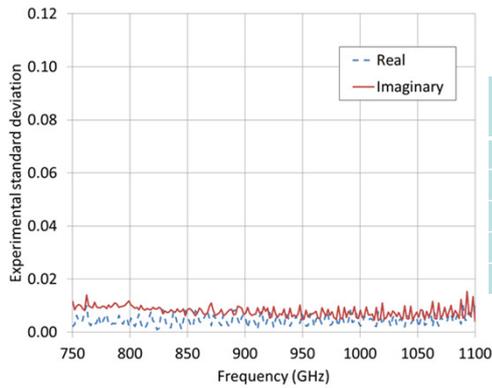
$$s^2(\Gamma_{I_i}) = \frac{1}{n-1} \sum_{j=1}^n (\Gamma_{I_j} - \bar{\Gamma}_I)^2$$

where

$$\bar{\Gamma}_I = \frac{1}{n} \sum_{i=1}^n \Gamma_{I_i}$$

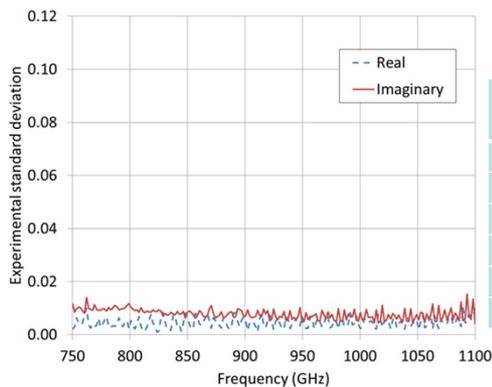
Experimental standard deviation,  $s(\Gamma_{I_i})$ , is the positive square root of  $s^2(\Gamma_{I_i})$

### Results – Near-matched load



Frequency (GHz)	$s(\Gamma_{R_i})$	$s(\Gamma_i)$
750.0	0.002 2	0.011 5
837.5	0.007 5	0.007 6
925.0	0.001 8	0.009 7
1012.5	0.002 5	0.004 5
1100.0	0.010 5	0.004 1

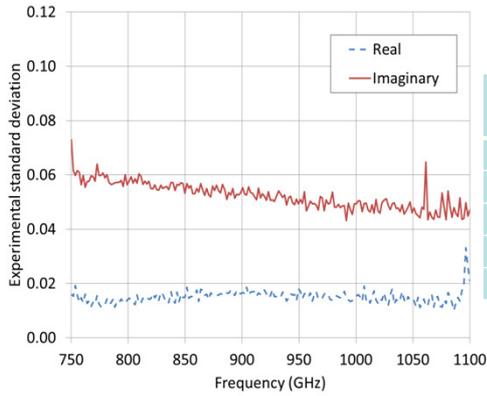
### Results – Near-matched load



Frequency (GHz)	$s(\Gamma_{R_i})$	$s(\Gamma_i)$
750.0	0.002 2	0.011 5
837.5	0.007 5	0.007 6
925.0	0.001 8	0.009 7
1012.5	0.002 5	0.004 5
1100.0	0.010 5	0.004 1
<b>Average</b>	<b>0.004 6</b>	<b>0.007 8</b>

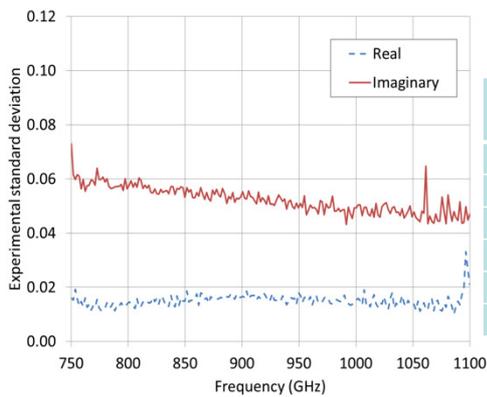
$$s(\Gamma_i) \approx 2 \times s(\Gamma_R)$$

### Results – Flush short



Frequency (GHz)	$s(\Gamma_R)$	$s(\Gamma_I)$
750.0	0.015 9	0.072 9
837.5	0.017 0	0.057 2
925.0	0.015 4	0.050 6
1012.5	0.012 9	0.046 3
1100.0	0.021 0	0.047 1

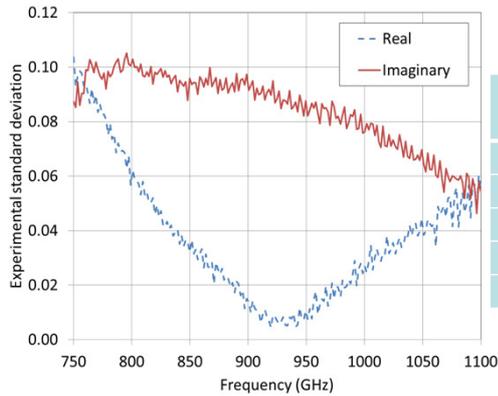
### Results – Flush short



Frequency (GHz)	$s(\Gamma_R)$	$s(\Gamma_I)$
750.0	0.015 9	0.072 9
837.5	0.017 0	0.057 2
925.0	0.015 4	0.050 6
1012.5	0.012 9	0.046 3
1100.0	0.021 0	0.047 1
<b>Average</b>	<b>0.015 0</b>	<b>0.052 3</b>

$$s(\Gamma_I) \approx 3.5 \times s(\Gamma_R)$$

### Results – Offset short



Frequency (GHz)	$s(\Gamma_R)$	$s(\Gamma_I)$
750.0	0.103 6	0.087 3
837.5	0.039 6	0.096 9
925.0	0.006 9	0.088 5
1012.5	0.030 3	0.072 5
1100.0	0.056 1	0.054 6

### Observations

Device	Nominal reflection coefficient, $\Gamma$	$s(\Gamma_R)$	$s(\Gamma_I)$	$s(\Gamma_R)$ & $s(\Gamma_I)$
Near-matched load	$ \Gamma  \approx 0$	0.005	0.008	$s(\Gamma_I) \approx 2 \times s(\Gamma_R)$
Flush short	$ \Gamma  \approx 1$ phase = $\pm 180^\circ$	0.015	0.052	$s(\Gamma_I) \approx 3.5 \times s(\Gamma_R)$
Offset short	$ \Gamma  \approx 1$ phase varies with frequency	0.01 $\rightarrow$ 0.10	0.05 $\rightarrow$ 0.10	$s(\Gamma_I)$ and $s(\Gamma_R)$ vary with frequency

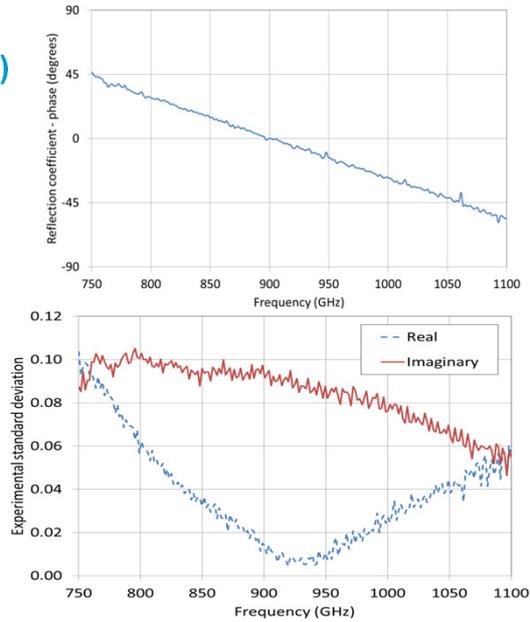
### Observations (contd)

Offset short: phase,  $\varphi$

750 GHz:  $\varphi \approx +45^\circ$

900 GHz:  $\varphi \approx 0^\circ$

1100 GHz:  $\varphi \approx -55^\circ$



### Observations (contd)

Repeatability can be represented as regions (i.e. areas) in the complex  $\Gamma$ -plane

$s(\Gamma_R) \neq s(\Gamma_I)$  suggests regions that are elliptical

The covariance of  $\Gamma_R$  and  $\Gamma_I$  is needed to fully define the ellipse:

$$s(\Gamma_R, \Gamma_I) = \frac{1}{(n-1)} \sum_{k=1}^n (\Gamma_{Rk} - \bar{\Gamma}_R)(\Gamma_{Ik} - \bar{\Gamma}_I)$$

## Observations (contd)

The ellipse can be calculated using the covariance matrix:

$$V = \begin{pmatrix} s^2(\Gamma_R) & s(\Gamma_R, \Gamma_I) \\ s(\Gamma_I, \Gamma_R) & s^2(\Gamma_I) \end{pmatrix}$$

The correlation coefficient can be calculated to indicate the degree of correlation between  $\Gamma_R$  and  $\Gamma_I$ :

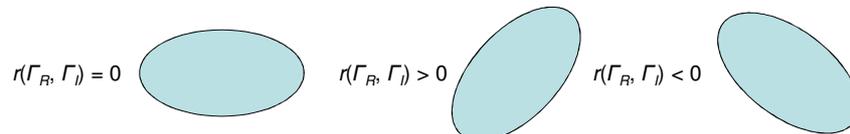
$$r(\Gamma_R, \Gamma_I) = \frac{s(\Gamma_R, \Gamma_I)}{s(\Gamma_R)s(\Gamma_I)}$$

## Observations (contd)

A correlation coefficient,  $r(\Gamma_R, \Gamma_I)$ , can have a value anywhere within the range:

$$-1 \leq r(\Gamma_R, \Gamma_I) \leq +1$$

The value of  $r(\Gamma_R, \Gamma_I)$  affects the orientation of the ellipse:

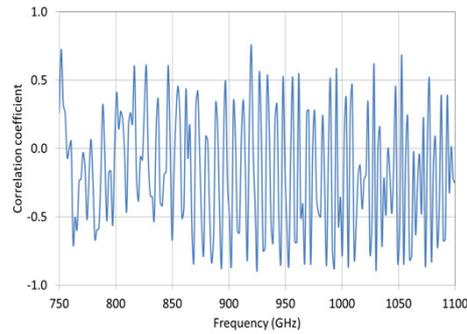


The correlation coefficient helps interpret the data

## Observations: Near-matched load

$$s(\Gamma_I) \approx 2 \times s(\Gamma_R)$$

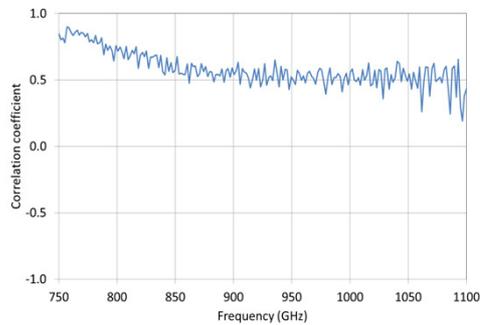
### Repeatability ellipses



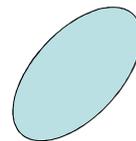
## Observations: Flush short

$$s(\Gamma_I) \approx 3.5 \times s(\Gamma_R)$$

### Repeatability ellipses

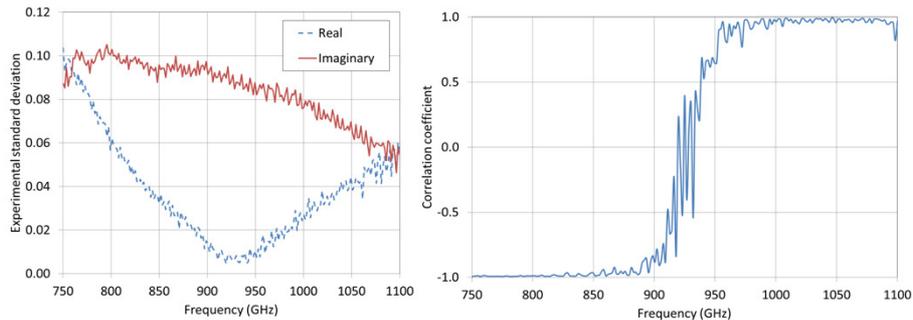


$$r(\Gamma_R, \Gamma_I) > 0$$



## Observations: Offset short

### Repeatability ellipses



## Uncertainty considerations

The generalized measurement model:

$$\mathbf{y} = f(\mathbf{x})$$

Applied to our situation, becomes:

$$\Gamma_M = f(\Gamma_1, \Gamma_2, \Gamma_3)$$

The uncertainty can be represented as:

$$\mathbf{V}_y = \mathbf{J} \mathbf{V}_x \mathbf{J}^T$$

$$V_y = J V_x J^T$$

### Uncertainty considerations - contd

$$V_y = \begin{pmatrix} u^2(\Gamma_{MR}) & u(\Gamma_{MR}, \Gamma_{MI}) \\ u(\Gamma_{MI}, \Gamma_{MR}) & u^2(\Gamma_{MI}) \end{pmatrix}$$

$$J = \begin{pmatrix} \partial f_R / \partial \Gamma_{1R} & \partial f_R / \partial \Gamma_{1I} & \partial f_R / \partial \Gamma_{2R} & \partial f_R / \partial \Gamma_{2I} & \partial f_R / \partial \Gamma_{3R} & \partial f_R / \partial \Gamma_{3I} \\ \partial f_I / \partial \Gamma_{1R} & \partial f_I / \partial \Gamma_{1I} & \partial f_I / \partial \Gamma_{2R} & \partial f_I / \partial \Gamma_{2I} & \partial f_I / \partial \Gamma_{3R} & \partial f_I / \partial \Gamma_{3I} \end{pmatrix}$$

$$V_y = J V_x J^T$$

### Uncertainty considerations - contd

$$V_x = \begin{pmatrix} u^2(\Gamma_{1R}) & u(\Gamma_{1R}, \Gamma_{1I}) & u(\Gamma_{1R}, \Gamma_{2R}) & u(\Gamma_{1R}, \Gamma_{2I}) & u(\Gamma_{1R}, \Gamma_{3R}) & u(\Gamma_{1R}, \Gamma_{3I}) \\ u(\Gamma_{1I}, \Gamma_{1R}) & u^2(\Gamma_{1I}) & u(\Gamma_{1I}, \Gamma_{2R}) & u(\Gamma_{1I}, \Gamma_{2I}) & u(\Gamma_{1I}, \Gamma_{3R}) & u(\Gamma_{1I}, \Gamma_{3I}) \\ u(\Gamma_{2R}, \Gamma_{1R}) & u(\Gamma_{2R}, \Gamma_{1I}) & u^2(\Gamma_{2R}) & u(\Gamma_{2R}, \Gamma_{2I}) & u(\Gamma_{2R}, \Gamma_{3R}) & u(\Gamma_{2R}, \Gamma_{3I}) \\ u(\Gamma_{2I}, \Gamma_{1R}) & u(\Gamma_{2I}, \Gamma_{1I}) & u(\Gamma_{2I}, \Gamma_{2R}) & u^2(\Gamma_{2I}) & u(\Gamma_{2I}, \Gamma_{3R}) & u(\Gamma_{2I}, \Gamma_{3I}) \\ u(\Gamma_{3R}, \Gamma_{1R}) & u(\Gamma_{3R}, \Gamma_{1I}) & u(\Gamma_{3R}, \Gamma_{2R}) & u(\Gamma_{3R}, \Gamma_{2I}) & u^2(\Gamma_{3R}) & u(\Gamma_{3R}, \Gamma_{3I}) \\ u(\Gamma_{3I}, \Gamma_{1R}) & u(\Gamma_{3I}, \Gamma_{1I}) & u(\Gamma_{3I}, \Gamma_{2R}) & u(\Gamma_{3I}, \Gamma_{2I}) & u(\Gamma_{3I}, \Gamma_{3R}) & u^2(\Gamma_{3I}) \end{pmatrix}$$

$$V_x = \begin{pmatrix} V_{\Gamma_1} & 0 & 0 \\ 0 & V_{\Gamma_2} & 0 \\ 0 & 0 & V_{\Gamma_3} \end{pmatrix}$$

where

$$V_{\Gamma_1} = \begin{pmatrix} u^2(\Gamma_{1R}) & u(\Gamma_{1R}, \Gamma_{1I}) \\ u(\Gamma_{1I}, \Gamma_{1R}) & u^2(\Gamma_{1I}) \end{pmatrix} \text{ etc}$$

## Summary

- Measurement repeatability in WM-250 (750 GHz to 1100 GHz)
- Data analyzed in terms of Real & Imaginary components
- Repeatability depends on the device – ‘worst’ for offset short
- Data visualization (i.e. repeatability ellipses) used to facilitate understanding of the measurement error mechanisms
- Application to uncertainty evaluation techniques
- General method – applicable to other waveguide bands

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